

Перв. примен.		Зана	Поз. обозначе– ние	Наименование	Кол.	Примечание
				Конденсаторы		
			C1	Cap, 0.01uF, 10%, 50V, 0603, X7R, -55 to +125 (C1608X7R1H103K)	1	TDK
			C2C5	Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	4	Hitano
			C6	Cap, 0.01uF, 10%, 50V, 0603, X7R, -55 to +125 (C1608X7R1H103K)	1	TDK
\vdash			C 7	Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	1	Hitano
			C8	Cap Tant, 100uF, 20V, 20%, D, -55 to +125 (T491D107K020AT)	1	Kemet
			C9	Cap, 0.01uF, 10%, 50V, 0603, X7R, -55 to +125 (C1608X7R1H103K)	1	TDK
2			C10	Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	1	Hitano
Cnpaß. Nº			C11	Cap, 0.01uF, 10%, 50V, 0603, X7R, -55 to +125 (C1608X7R1H103K)	1	TDK
ت			C12,C13	Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	2	Hitano
			C14	Cap, 100pF, 5%, 50V, 0603, COG, -55 to +125 (0603N101J500N)	1	Hitano
			C15	Сар, 0.01uF, 10%, 50V, 0603, X7R, –55 to +125 (С1608X7R1H103K)	1	TDK
			C16	Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	1	Hitano
			C17	Cap, 0.01uF, 10%, 50V, 0603, X7R, -55 to +125 (C1608X7R1H103K)	1	TDK
			C18	Cap, 0.33uF, 10%, 16V, 0603, X7R, -55 to +125 (0603B334K160N)	1	Hitano
			C19	Сар, Elec, 10uF, 200V, 20%, Dia—10mm,	1	Rubycon
dama				-40 to +105 (200WXA10MEFCT810X9)		
Подп. и		C20,C21		Cap Tant, 100uF, 20V, 20%, D, -55 to +125 (T491D107K020AT)	2	Kemet
			C22	Cap Tant, 10uF, 10V, 10%, A, -55 to +125 (T491A106K010AT)	1	Kemet
, C		C23		Cap, 0.1uF, 10%, 50V, 0603, X7R, -55 to +125 (0603B104K500N)	1	Hitano
Инв. № дубл.						
ΛHĎ. N				Микросхемы		
\vdash	\dashv	DA1		LM317BD2TR4G IC, PMIC, LDO, to 40Vin, 1,237 Vout, 1,5 A,	1	ON Semiconductor
Взам. инв. №				–40 to +125		
30M. I		DA2		LM3478MM/NOPB PMIC, DC-DC, 2.9740Vin, 8-MSOP, -40 to +125	1	TI
8			DA3	LCA182S Relay, 350V, 120mA, 350hm, AC/DC, SMD-6, -40 to +85	1	IXYS
밑	ŀ	DA4		LM317BD2TR4G IC, PMIC, LDO, to 40Vin, 1,237 Vout, 1,5 A,	1	ON Semiconductor
Подп. и дата	Ī	-40 to +125				
		Изм	/lucm № ð	АЗРО 94A 01.060.0	00.	910ПЭ3
Инв. № подл.		Разр	аб. Жук	Модили блока	/lum.	Лист Листов
	Пров. Т. контр Н.контр.		нтр Коренс	·	3/	<u> 1 5</u> AO "АЭРОМАШ"
Z		Утв. Гейст		Гіеречень элеменіно		Формат Л.

Зона	Поз. обозначе– ние	Наименование	Кол.	Примечание	
	DD1	ADM4853ARZ Interface, 422/485, 10Mbps, 5V, Half, SOIC-8,	1	AD	
		-40 to +85			
	DD2	LMC555CMX Timer/Osccillator, 3MHz, 1,5V-15V, 8 - SOIC,	1	TI	
		-40 to 85			
	DD3,DD4	ADM4853ARZ Interface, 422/485, 10Mbps, 5V, Half, SOIC-8,	2	AD	
		-40 to +85			
	DD5,DD6	LMC555CMX Timer/Osccillator, 3MHz, 1,5V-15V, 8 - SOIC,	2	TI	
		-40 to 85			
	DD7	ADM4853ARZ Interface, 422/485, 10Mbps, 5V, Half, SOIC-8,	1	AD	
		-40 to +85			
	FU1	Предохранитель MF-R500 PTC, 30Vmax, 40Amax, 5Ahold, 10Atrip,	1	Bourns	
		MF-R500, -40 to +85			
	K1K4	Реле V23086-C1001-A403 Relay, 12V, 567mW, 30A, -40 to +125	4	TE	
		Катушки индуктивности			
	L1	7447709471 470 uH, 20%, 1.4A, 560m0hm, SMT, 12x12, -40 to +125	1	Wurth Electronics	
	L2	100uH, 5A, 110 m0hm, 20%, SMD, -55 to+155 (IHLP6767GZER101M11)	1	Vishay	
		Резисторы			
	R1	Res, 200 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J200R)	1		
	R2	Res, 120 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J120R)	1	FaithfulLink	
	R3	Res, 10 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F10K)	1	FaithfulLink	
	R4	Res, 2.2 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J2R2)	1	FaithfulLink	
	R5	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink	
	R6	Res, 120 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J120R)	1	FaithfulLink	
	R7	Res, 10 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F10K)	1	FaithfulLink	
	R8	Res, 100 Ohm, 10W, 5%, 2010 (CHF2010CNP101RX)	1	Bourns	
	R9	Res, 2.2 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J2R2)	1	FaithfulLink	
	R10	Res, 22 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F22K)	1	FaithfulLink	
	R11	Res, 200 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J200R)	1		
		Λ 3DN Q <i>I</i> . Λ N1N4N N	$\cap \cap$	Q10033 /ucm	
Изм.	Мзм. /lucm № докум. Подп. Дата АЭРО 94А 01.060.000.910ПЭЗ Н				

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Подп. и дата

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Зона	Поз. обозначе– ние	Наименование	Кол.	Примечание
	R12	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
	R13	Res, 51 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F51K)	1	FaithfulLink
	R14	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
	R15	Res, 150 k0hm, 0.1W, 1%, 0603, -55 to +155 (RC0603F150K)	1	FaithfulLink
	R16	Res, 10 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F10K)	1	FaithfulLink
	R17	Res, 100 k0hm, 0.1W, 1%, 0603, -55 to +155 (RC0603F100K)	1	FaithfulLink
	R18	Res, 4.7 Ohm, 0.5W, 5%, 1206, –55 to +155 (CRM1206–JW–4R7ELF)	1	Bourns
	R19	Res, 2.2 Ohm, 0.1W, 5%, 0603, -55 to +155 (RC0603J2R2)	1	FaithfulLink
	R20	Res, 120 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J120R)	1	FaithfulLink
	R21	Res, 200 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J200R)	1	
	R22,R23	Res, 10 k0hm, 0.1W, 1%, 0603, -55 to +155 (RC0603F10K)	2	FaithfulLink
	R24	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
	R25	Res, 2.2 Ohm, 0.1W, 5%, 0603, –55 to +155 (RC0603J2R2)	1	FaithfulLink
	R26	Res, 47 m0hm, 2W, 1%, 2512, -55 to +155 (RCWE251247L0FNEA)	1	VISHAY
	R27	Res, 100 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F100K)	1	FaithfulLink
	R28,R29	Res, 51 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F51K)	2	FaithfulLink
	R30	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
	R31	Res, 560 Ohm, 2W, 5%, PRO2, -55 to +155 (PRO2000205600JR500)	1	Vishay
	R32	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
	R33	Res, 2.4k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F2K4)	1	FaithfulLink
	R34	Res, 7.32 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F7K32)	1	FaithfulLink
	R35	Res, 1 k0hm, 0.1W, 1%, 0603, –55 to +155 (RC0603F1K)	1	FaithfulLink
		Диоды		
	VD1	BAT54ST Rectifier, Dual, 30Vr, 200mA, 1Vf, S0T-23, -55 to +150	1	Diodes Incorporated
	VD2	MBRS3200T3 Schottky, 200Vr, 3A, 840mVf, D0214AA, -65 to +175	1	ON Semiconductor
-	VD3	50WQ04FN Schottky, 40Vr, 5.5A, 510mVf, T0252, -40 to +150	1	International Rectifier
	VD4	SMBJ7.0CA Bi, 7Vrs, 12Vc, 600W, D0214AA, -55 to +150	1	Fairchild
	VD5	BAT54ST Rectifier, Dual, 30Vr, 200mA, 1Vf, S0T-23, -55 to +150	1	Diodes Incorporated
	VD6	MBRS3200T3 Schottky, 200Vr, 3A, 840mVf, D0214AA, -65 to +175	1	ON Semiconductor
	VD7	MURS320T3G Rectifier, 200Vr 1A, 875mV, D0-214AB, -65 to +175	1	ON Semiconductor
	VD8,VD9	MBRS3200T3 Schottky, 200Vr, 3A, 840mVf, D0214AA, -65 to +175	2	ON Semiconductor
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Зона	Поз. обозначе– ние	Наименование	Кол.	Примечание	
		Транзисторы	IЫ ПО		
	VT1VT3	P3203CMG N-Channel, 30V, 6A, 32m0hm, S0T-23	3	NIKO-SEM	
	VT4	IPD600N25N3 N-Channel, 250V, 25A, 60m0hm, D-PAK, -55 to +175	1	Infineon	
	VT5	IRLML6402 P-Channel, -20V, -3.7A, 65m0hm, S0T-23	1	International Rectifi	
	VT6	P3203CMG N-Channel, 30V, 6A, 32m0hm, S0T-23	1	NIKO-SEM	
	X1X42		1	Монтажное отверсти	
		Плата печатная АЭРО 01.060.000.911	1		
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